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Kind regards,

Team Nexperia

Schottky barrier single diode in small SOD123F package 25 July 2012 Product data sheet

1. Product profile

1.1 General description

Planar Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a SOD123F small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Inverse-polarity protection

1.4 Quick reference data

Table 1. C	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
l _F	forward current		-	-	200	mA
V _R	reverse voltage		-	-	30	V
V _F	forward voltage	I _F = 10 mA; pulsed; t _p ≤ 300 μs; $\delta \le 0.02$; T _{amb} = 25 °C	-	-	400	mV

2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode[1]		K 🛃 A
2	А	anode		aaa-003679
			SOD123F	

[1] The marking bar indicates the cathode.





Schottky barrier single diode in small SOD123F package

Ordering information 3.

Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
BAT54H	SOD123F	plastic surface-mounted package; 2 leads	SOD123F

Marking 4.

Table 4. Marking codes	
Type number	Marking code
BAT54H	AG

5. **Limiting values**

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _R	reverse voltage			-	30	V
l _F	forward current			-	200	mA
I _{FRM}	repetitive peak forward current	t _p ≤ 1 s; δ ≤ 0.5		-	300	mA
I _{FSM}	non-repetitive peak forward current	$t_p \le 10 \text{ ms; } T_{j(init)} = 25 ^\circ\text{C}$		-	600	mA
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1]	-	375	mW
Tj	junction temperature			-	125	°C
T _{amb}	ambient temperature			-65	125	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

Thermal characteristics 6.

Table 6. The	ermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	330	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[2]	-	-	70	K/W
BAT54H		All information provided in this document is subject to legal disclaimers.			© NXF	B.V. 2012. All	rights reserved

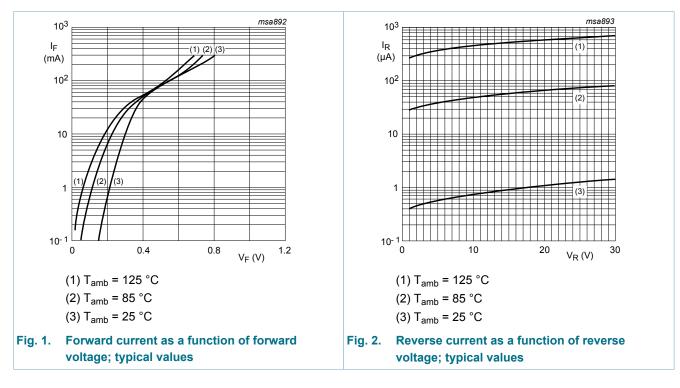
Schottky barrier single diode in small SOD123F package

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Soldering point of cathode tab.

7. Characteristics

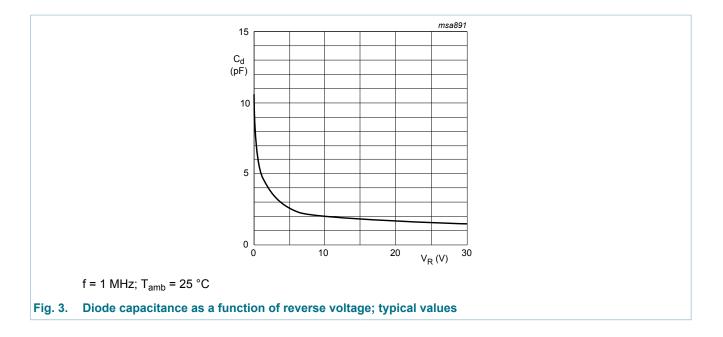
Table 7. Cha	racteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F forward voltage	forward voltage	I_F = 0.1 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02 ; T _{amb} = 25 °C	-	-	240	mV
		I_F = 1 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02 ; T _{amb} = 25 °C	-	-	320	mV
		I _F = 10 mA; pulsed; t _p ≤ 300 μs; $\delta \le 0.02$; T _{amb} = 25 °C	-	-	400	mV
		I _F = 30 mA; pulsed; t _p ≤ 300 μs; $\delta \le 0.02$; T _{amb} = 25 °C	-	-	500	mV
		I _F = 100 mA; pulsed; t _p ≤ 300 μs; $\delta \le 0.02$; T _{amb} = 25 °C	-	-	800	mV
I _R	reverse current	V _R = 25 V; T _{amb} = 25 °C	-	-	2	μA
C _d	diode capacitance	f = 1 MHz; T_{amb} = 25 °C; V_R = 1 V	-	-	10	pF



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Schottky barrier single diode in small SOD123F package

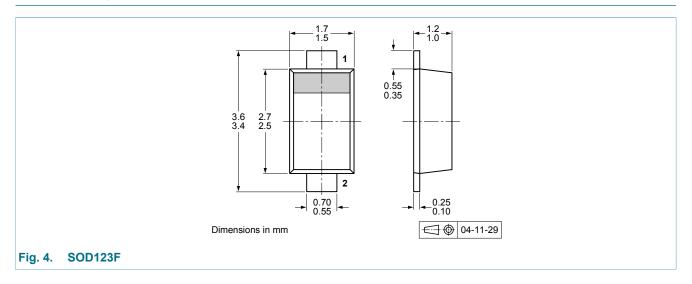


8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

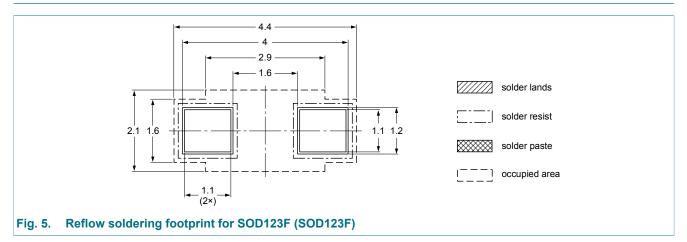
9. Package outline



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Schottky barrier single diode in small SOD123F package

10. Soldering



11. Revision history

Table 8. Revision h	nistory				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
BAT54H v.3	20120725	Product data sheet	-	BAT54H v.2	
 Modifications: The format of this document has been redesigned to comply with the new identity guideline of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Section "Test information" added 					
BAT54H v.2	20100128	Product data sheet	-	BAT54H v.1	
BAT54H v.1	20050407	Product data sheet	-		

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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or [1] completing a design.

The term 'short data sheet' is explained in section "Definitions". [2]

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Product data sheet

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